

综述

半导体可饱和吸收镜作为被动调Q吸收体的发展状况

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摘要 简介了近年来发展起来的若干种新型固体激光器被动调Q用吸收体: 掺Cr⁴⁺系列, Cr, Nd:YAG自调Q激光晶体, 人眼安全激光器被动调Q用吸收体, GaAs吸收体, 半导体可饱和吸收镜。着重介绍了固体激光器和光纤激光器调Q用半导体可饱和吸收镜的原理、研制方法及应用状况。

关键词 [半导体可饱和吸收镜](#) [固体激光器](#) [调Q用吸收体](#)

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The Development of Semiconductor Saturable Absorption Mirror as Passive Q-switching Absorber

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Abstract Some types of novel absorbers for solid state laser passive Q-switching developed in recent years are introduced, such as Cr⁴⁺ doped series,Cr,Nd:YAG self Q-switching laser crystal,absorber for Q-switching eye safe lasers, GaAs absorber, semiconductor saturable absorption mirror.The principle, application and exploratory development of semiconductor saturable absorption mirrors for passive Q-switching of solid state lasers and fiber lasers are emphasized.

Key words [semiconductor saturable absorption mirror](#) [solid-state laser](#) [Q-switching absorber](#)

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